

# isc Silicon PNP Power Transistor

# 2SA1094

# DESCRIPTION

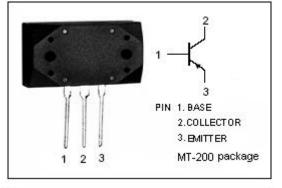
- Collector-Emitter Breakdown Voltage-V<sub>(BR)CEO</sub>= -140V(Min)
- Good Linearity of h<sub>FE</sub>
- Complement to Type 2SC2564
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

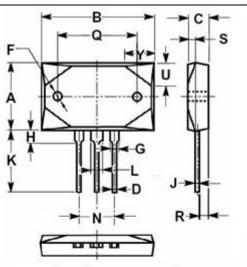
## APPLICATIONS

- · Power amplifier applications
- Recommended for 80W high-fidelity audio frequency amplifier output stage

SYMBOL	PARAMETER	VALUE	UNIT
V <sub>CBO</sub>	Collector-Base Voltage	-140	V
Vceo	Collector-Emitter Voltage	-140	V
V <sub>EBO</sub>	Emitter-Base Voltage	-5	V
lc	Collector Current-Continuous	-12	A
le	Emitter Current-Continuous	12	А
Pc	Collector Power Dissipation @ Tc=25°C	120	W
TJ	Junction Temperature	150	°C
T <sub>stg</sub>	Storage Temperature Range	-55~150	°C

# ABSOLUTE MAXIMUM RATINGS(Ta=25℃)





	m	m
DIM	MIN	MAX
Α	21.00	21.70
В	35.80	36.70
С	5.60	6.20
D	1.04	1.07
F	3.10	3.50
G	1.90	2.40
H	3.60	4.00
J	0.55	0.85
К	20.00	20.80
L	2.90	3.40
N	10.50	11.10
Q	24.00	24.50
R	2.90	3.30
S	2.00	2.20
U	6.90	7.10
Y	8.90	9.10

# isc website: www.iscsemi.com

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# **ELECTRICAL CHARACTERISTICS**

#### $T_c=25^{\circ}C$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	МАХ	UNIT
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = -10mA; I <sub>B</sub> = 0	-140			V
V <sub>(BR)EBO</sub>	Emitter-Base Breakdown Voltage	I <sub>E</sub> = -0.01A; I <sub>C</sub> = 0	-5			V
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = -5A; I <sub>B</sub> = -0.5A			-2.0	V
V <sub>BE(on)</sub>	Base-Emitter On Voltage	I <sub>C</sub> = -5A; V <sub>CE</sub> = -5V			-2.0	V
I <sub>CBO</sub>	Collector Cutoff Current	V <sub>CB</sub> = -140V ; I <sub>E</sub> = 0			-50	μA
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = -5V; I <sub>C</sub> = 0			-50	μA
h <sub>FE-1</sub>	DC Current Gain	I <sub>C</sub> = -1A ; V <sub>CE</sub> = -5V	55		240	
h <sub>FE-2</sub>	DC Current Gain	I <sub>C</sub> = -5A ; V <sub>CE</sub> = -5V	30			

### h<sub>FE-1</sub> Classifications

R	о	Y	
55-110	80-160	120-240	

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